

FORM PTO-1449	ATTY. DKT NO.	01-235	SER. NO.
	APPLICANT	NAITO et al.	
	FILING DATE	December 10, 2001	GROUP 1775

## REFERENCE DESIGNATION

## U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
SSS	5,679,153 (Discussed on page 2 of the spec.)	Oct. 21, 1997	Dmitriev et al.		
SSS	6,153,165 (Corresponding to JP-A-10-324600 which is discussed on page 2 of the spec.)	Nov. 28, 2000	Tanino et al.		
SSS	6,214,108 (Corresponding to JP-A-2000-44398 which is discussed on page 2 of the spec.)	Apr. 10, 2001	Okamoto et al.		
SSS	6,153,166	Nov. 28, 2000	Tanino		
SSS	6,203,772	Mar. 20, 2001	Tanino et al.		

## FOREIGN PATENT DOCUMENTS

## TRANSLATION

	DOCUMENT NUMBER	DATE	COUNTRY	NAME	CLASS	SUB CLASS	YES	NO
SSS	JP-A-2000-34198 *	2/2/00	JAPAN				X	

\* Full English text of the JP Document will be available in machine-translated form from JP (Japanese Patent Office) English language web site at <http://www1.ipdl.jpo.go.jp/PA1/cgi-bin/PA1INDEX>.

## OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

SSS	Kamata et al., "Migration of shifting in epitaxial growth of thick 4H-SiC," <u>Abstract of the Lecture of 47<sup>th</sup> Japan Society of Applied Physics Related Association</u> , separate Volume 1, p.407, No. 29p-YF-6, March 2000. (Discussed on page 2 of the spec.)
EXAMINER	DATE CONSIDERED
<i>Stephen Stern</i>	6/23/03